



## 2SA2013/2SC5566

### DC/DC Converter Applications

#### Applications

- Relay drivers, lamp drivers, motor drivers, strobes.

#### Features

- Adoption of FBET and MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products.
- High allowable power dissipation.

#### Specifications

( ) : 2SA2013

##### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		(-50)80	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-50)	V
Emitter-to-Base Voltage	$V_{EBO}$		(-6)	V
Collector Current	$I_C$		(-4)	A
Collector Current (Pulse)	$I_{CP}$		(-7)	A
Base Current	$I_B$		(-600)	mA
Collector Dissipation	$P_C$	Mounted on a ceramic board (250mm <sup>2</sup> ×0.8mm)	1.3	W
		$T_c=25^\circ\text{C}$	3.5	W
Junction Temperature	$T_j$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

##### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=(-)40\text{V}, I_E=0$			(-1)	μA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=(-)4\text{V}, I_C=0$			(-1)	μA
DC Current Gain	$h_{FE}$	$V_{CE}=(-)2\text{V}, I_C=(-)500\text{mA}$	200		560	
Gain-Bandwidth Product	$f_T$	$V_{CE}=(-)10\text{V}, I_C=(-)500\text{mA}$		(360)		MHz
				400		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(24)15		pF

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Marking : 2SA2013 : AT 2SC5566 : FC

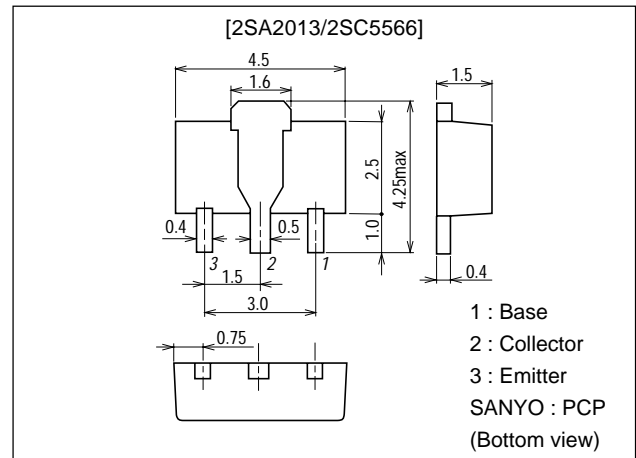
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#### Package Dimensions

unit:mm

2038A

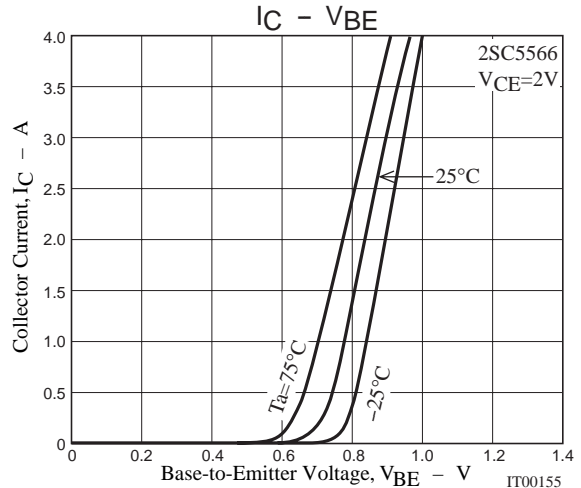
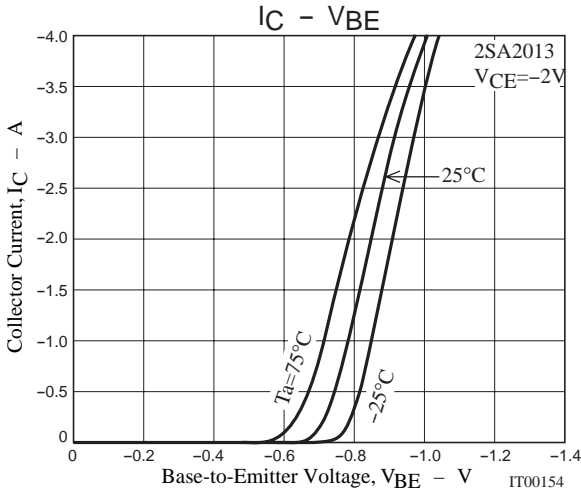
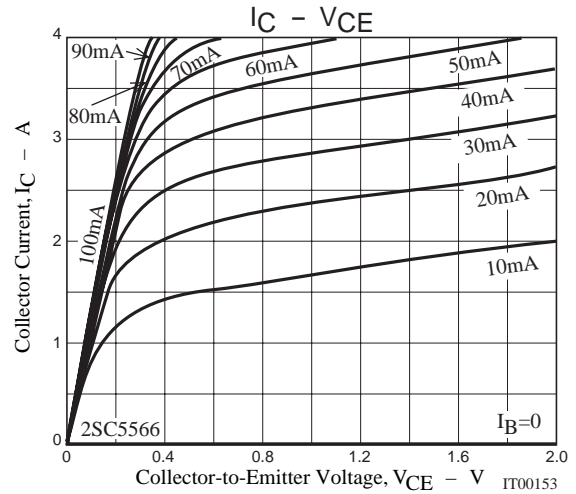
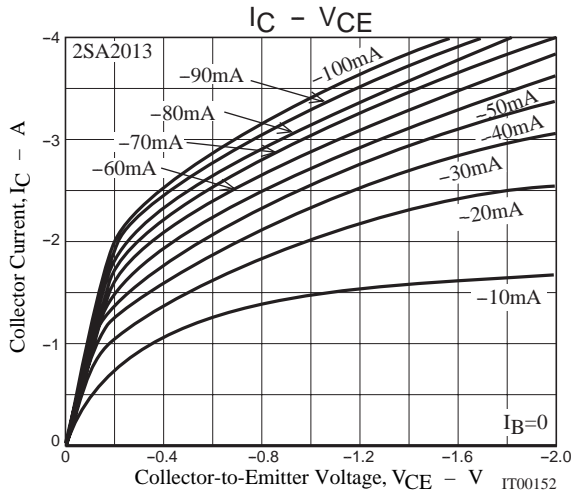
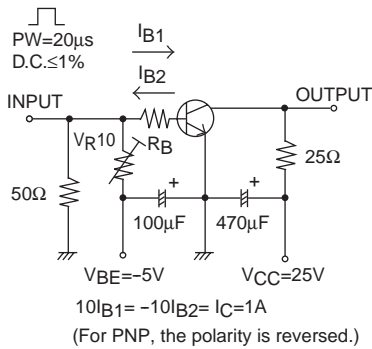


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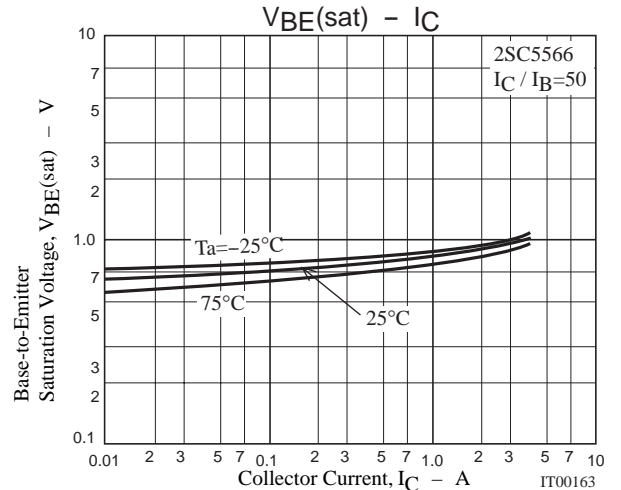
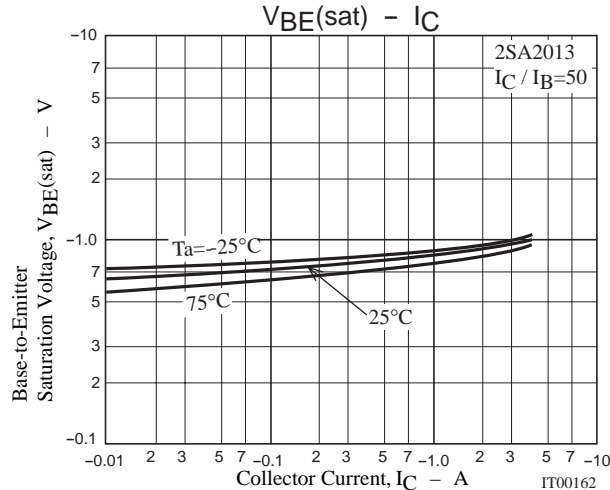
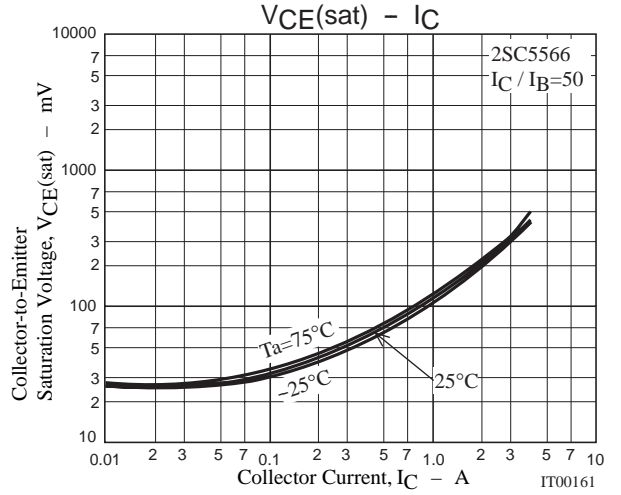
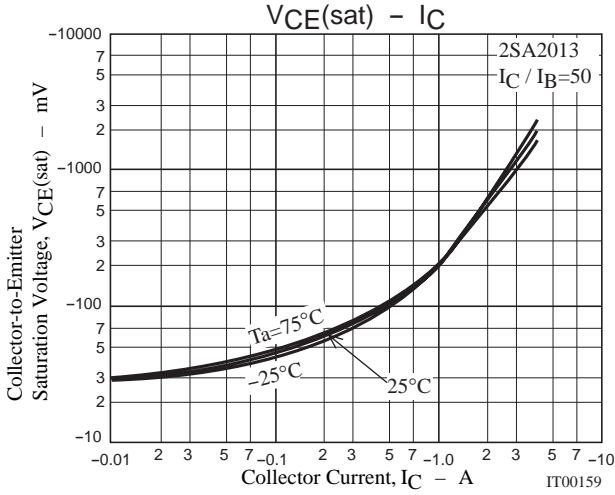
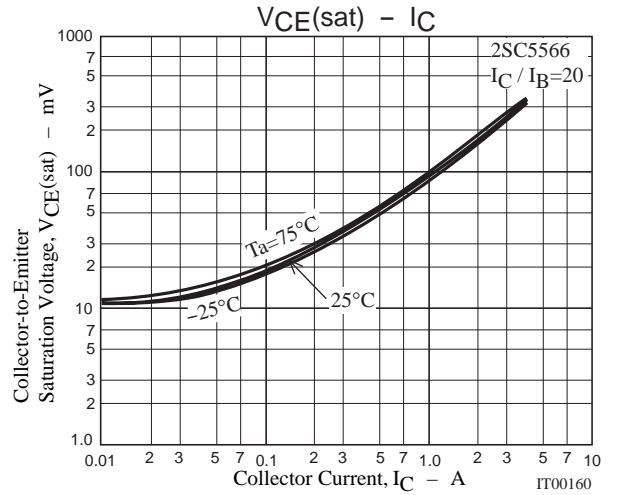
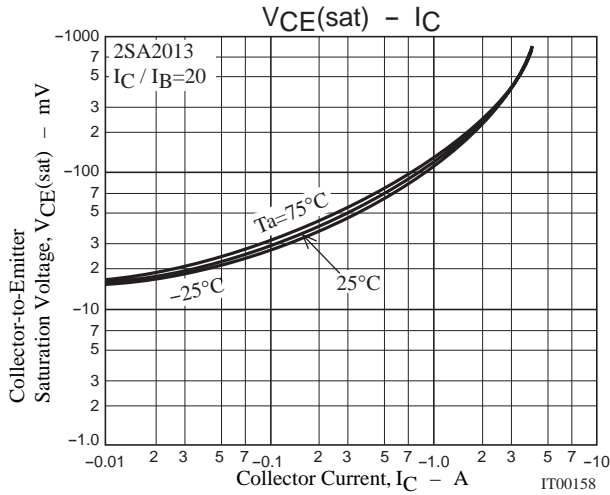
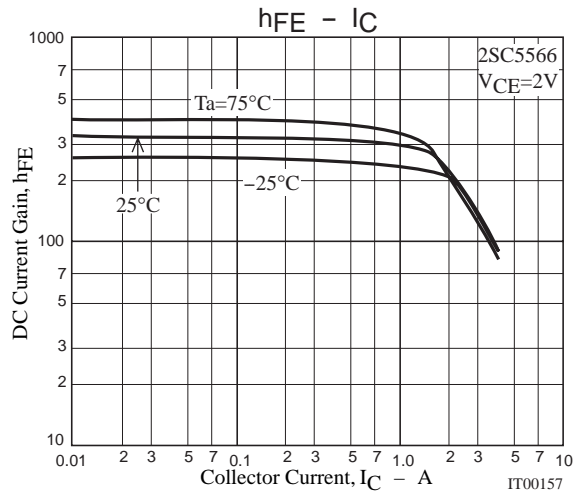
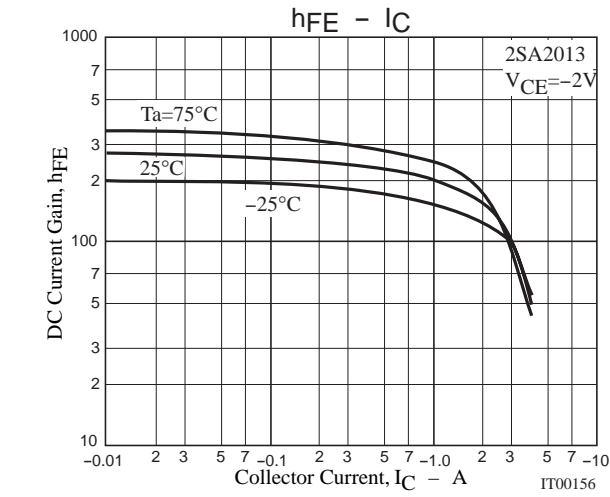
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)1A, I_B=(-)50mA$		(-105)	(-180)	mV
				85	130	mV
				(-200)	(-340)	mV
		$I_C=(-)2A, I_B=(-)100mA$		150	225	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		(-)0.89	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-50)			V
			80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)6			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		(30)35		ns
Storage Time	$t_{stg}$	See specified Test Circuit		(230)		ns
				300		ns
Fall Time	$t_f$	See specified Test Circuit		(15)20		ns

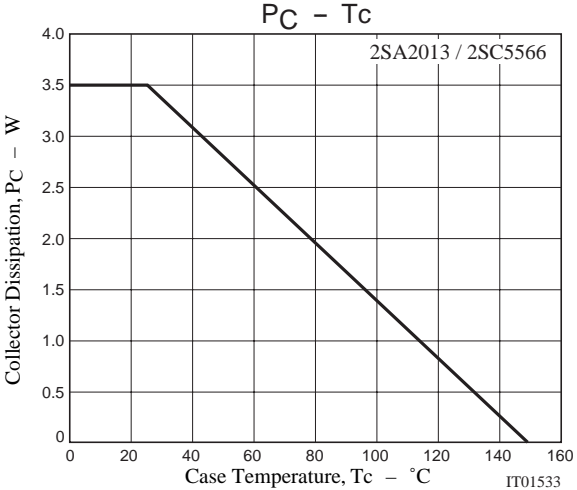
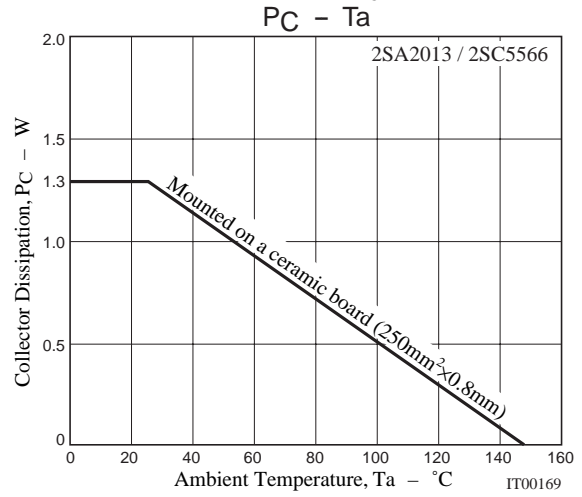
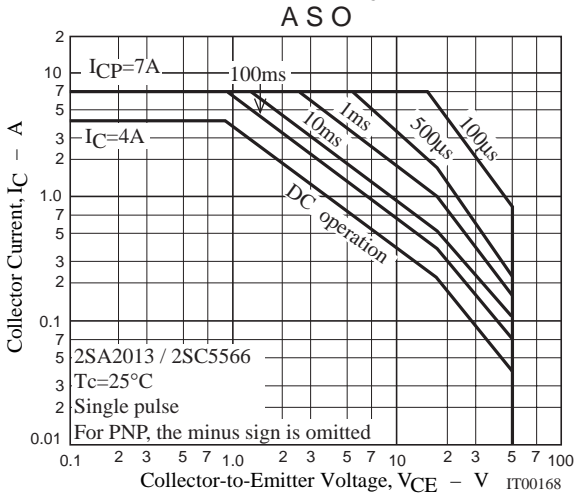
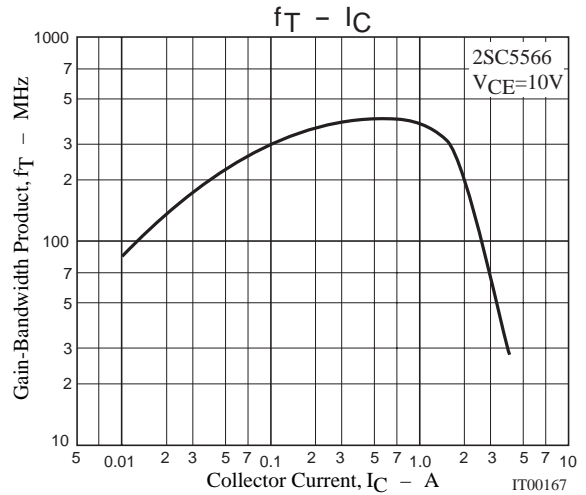
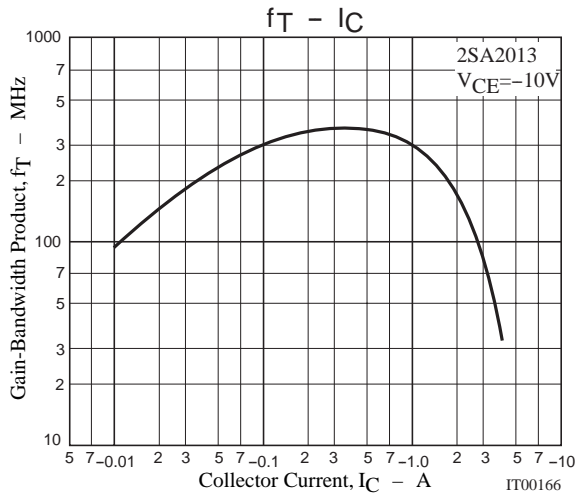
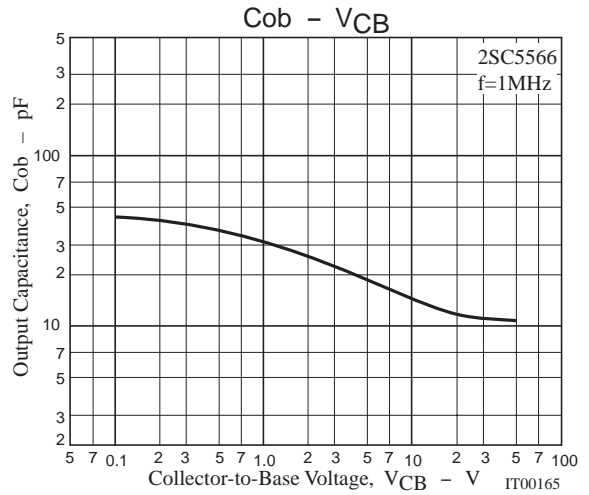
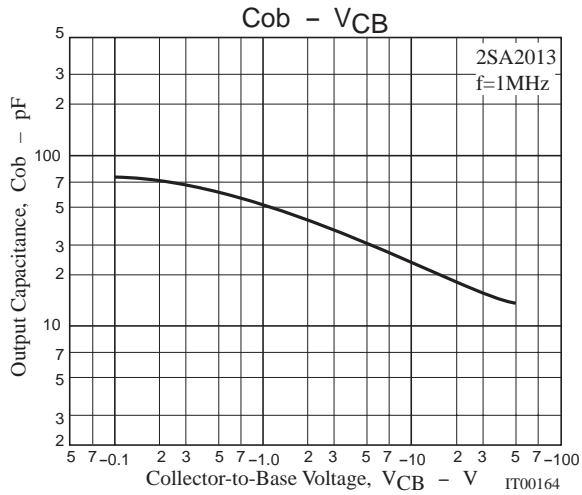
## Switching Time Test Circuit



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